

Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200 V

Forward Current - 8 A

FEATURES

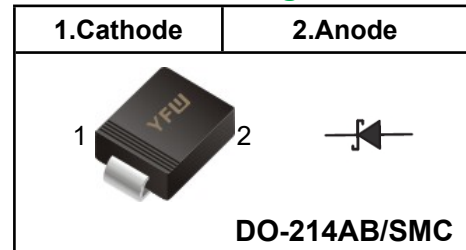
- ◆ Metal silicon junction, majority carrier conduction
- ◆ For surface mounted applications
- ◆ Low power loss, high efficiency
- ◆ High forward surge current capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- ◆ Case: DO-214AB/SMC
- ◆ Terminals: Solderable per MIL-STD-750, Method 2026
- ◆ Approx. Weight: 0.22g / 0.0077oz

Absolute Maximum Ratings and Electrical characteristics
 Ratings at 25 ° ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Pinning



Marking Code

SS82C	YFW SS82
SS84C	YFW SS84
SS86C	YFW SS86
SS88C	YFW SS88
SS810C	YFW SS810
SS812C	YFW SS812
SS815C	YFW SS815
SS820C	YFW SS820

Parameter	Symbols	SS82C	SS84C	SS86C	SS88C	SS810C	SS812C	SS815C	SS820C	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	40	60	80	100	120	150	200	V
Maximum RMS voltage	V_{RMS}	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	V_{DC}	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	8.0								A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed On Rated Load (JEDEC method)	I_{FSM}	180								A
Maximum Instantaneous Forward Voltage at 8 A	V_F	0.45	0.55	0.70		0.85				V
Maximum Instantaneous Reverse Current at Rated DC Reverse Voltage <small>$T_A = 25^{\circ}C$ $T_A = 100^{\circ}C$</small>	I_R	1.0 50								mA
Typical Junction Capacitance ⁽¹⁾	C_j	600			400					pF
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$	35								°C/W
Operating Junction Temperature Range	T_j	-55 ~ +150								°C
Storage Temperature Range	T_{stg}	-55 ~ +150								°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

Fig.1 Forward Current Derating Curve

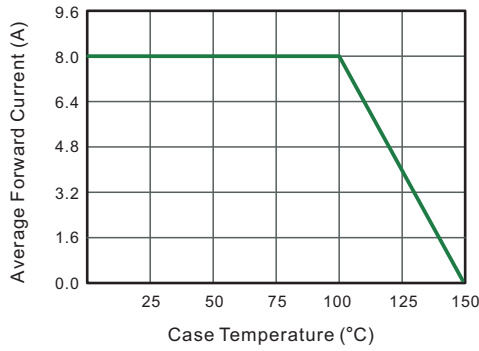


Fig.2 Typical Reverse Characteristics

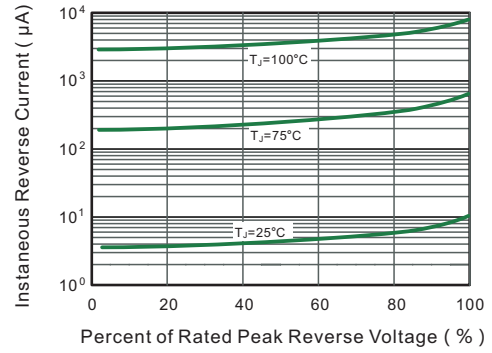


Fig.3 Typical Forward Characteristic

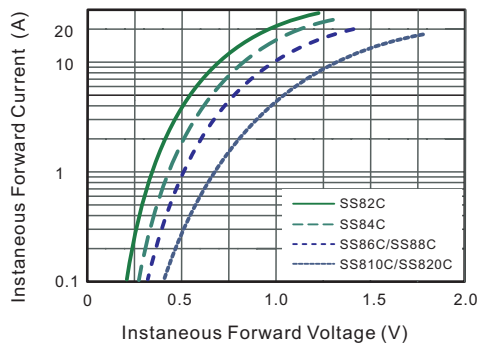


Fig.4 Typical Junction Capacitance

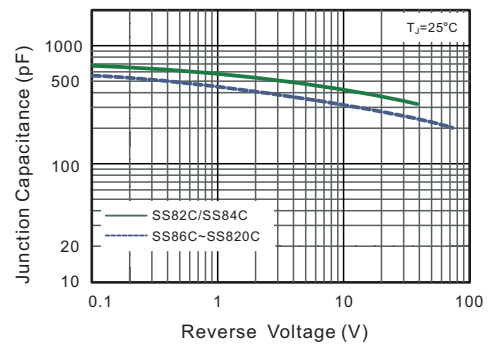


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

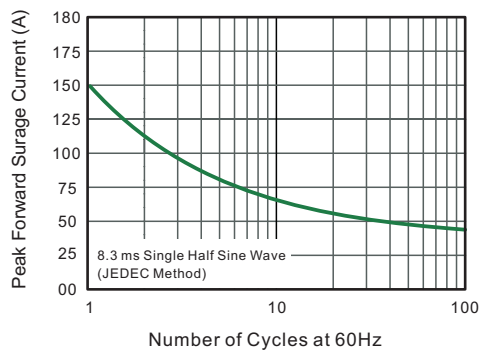
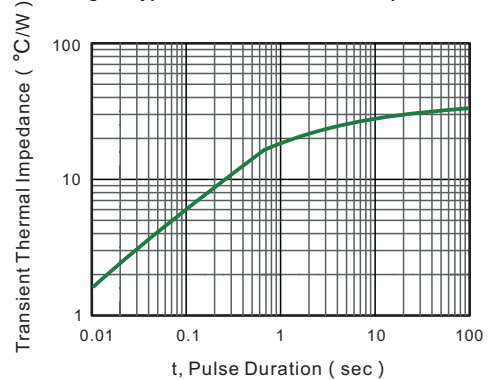
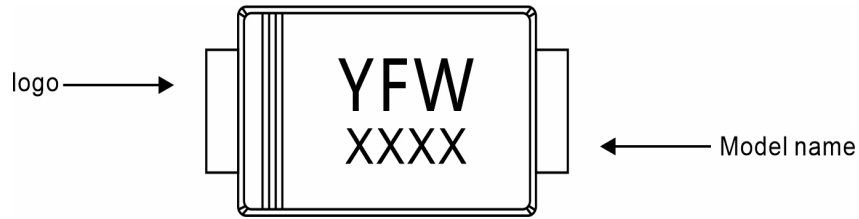


Fig.6- Typical Transient Thermal Impedance



Marking Diagram



Ordering information

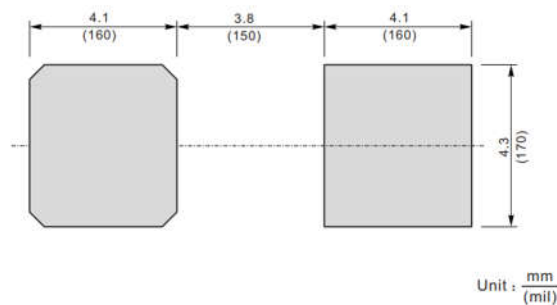
Package	Packing Description	Packing Quantity
DO-214AB SMC	Tape/Reel, 13" reel	3000PCS/Reel 30000PCS/Carton

Package Dimensions

DO-214AB SMC

Dim.	Millimeter(mm)		mil	
	Min.	Max.	Min.	Max.
A	2.00	2.62	79	103
E	6.5	7.0	256	276
D	5.6	6.2	220	244
E ₁	7.6	8.0	299	315
A ₁	0.05	0.21	2.0	8.3
C	0.15	0.31	5.9	12
L	0.9	1.6	35	63
b	2.75	3.25	108	128

The recommended mounting pad size



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